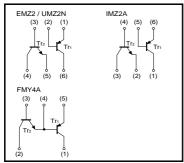
# Power management (dual transistors)

# EMZ2 / UMZ2N / FMY4A / IMZ2A

#### ● Feature

1) Both a 2SA1037AK chip and 2SC2412K chip in a EMT or UMT or SMT package.

### Equivalent circuits



#### ●Absolute maximum ratings (Ta = 25°C)

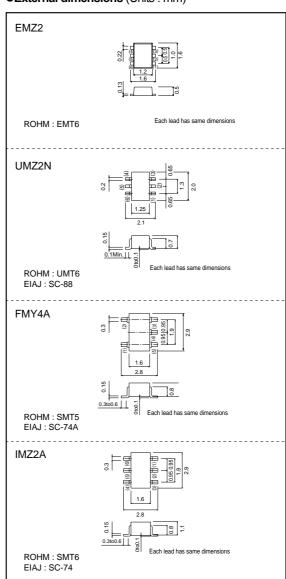
Parameter		Completed	Limits		Unit	
		Symbol	Tr <sub>1</sub>	Tr <sub>2</sub>	Unit	
Collector-base voltage		Vсво	-60	60	V	
Collector-emitter voltage		Vceo	-50	50	V	
Emitter-base voltage		Vebo	-6	7	V	
Collector current		lc	-150	150	mA	
Collector power dissipation	EMZ2, UMZ2N	Pc	150 (TOTAL)		mW	*1
	FMY4A, IMZ2A	''	300 (TOTAL)		IIIVV	*2
Junction temperature		Tj	150		°C	
Storage temperature		Tstg	-55~+150		°C	

<sup>\*1 120</sup>mW per element must not be exceeded.
\*2 200mW per element must not be exceeded.

## ●Package, marking, and packaging specifications

Part No.	EMZ2	UMZ2N	FMY4A	IMZ2A
Package	EMT6	UMT6	SMT5	SMT6
Marking	Z2	Z2	Y4	Z2
Code	T2R	TR	T148	T108
Basic ordering unit (pieces)	8000	3000	3000	3000

#### ●External dimensions (Units : mm)



# **Transistors**

# ●Electrical characteristics (Ta=25°C)

Tr₄

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic = -50μA	
Collector-emitter breakdown voltage	BVceo	-50	-	-	V	Ic = -1mA	
Emitter-base breakdown voltage	BVEBO	-6	-	-	V	Iε = -50μA	
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb = -60V	
Emitter cutoff current	Ієво	-	-	-0.1	μΑ	VEB = -6V	
Collector-emitter saturation voltage	VcE(sat)	-	-	-0.5	V	Ic/IB = -50mA/-5mA	
DC current transfer ratio	hfE	120	-	560	_	Vce = -6V , Ic = -1mA	
Transition frequency	f⊤	-	140	-	MHz	Vce = -12V , IE = 2mA , f = 100MHz *	
Output capacitance	Cob	-	4	5	pF	Vcb = -12V , IE = 0A , f = 1MHz	

<sup>\*</sup> Transition frequency of the device.

Tr2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	60	-	-	V	Ic = 50μA	
Collector-emitter breakdown voltage	BVceo	50	-	-	V	Ic = 1mA	
Emitter-base breakdown voltage	ВУєво	7	-	-	V	Iε = 50μA	
Collector cutoff current	Ісво	-	-	0.1	μА	Vcb = 60V	
Emitter cutoff current	Ієво	-	-	0.1	μА	VEB = 7V	
Collector-emitter saturation voltage	VcE(sat)	-	-	0.4	V	Ic/I <sub>B</sub> = 50mA/5mA	
DC current transfer ratio	hre	120	-	560	-	Vce = 6V , Ic = 1mA	
Transition frequency	f⊤	-	180	-	MHz	VcE = 12V , IE = -2mA , f = 100MHz *	
Output capacitance	Cob	-	2	3.5	pF	Vcs = 12V , IE = 0A , f = 1MHz	

<sup>\*</sup> Transition frequency of the device.

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